

L Number	Hits	Search Text	DB	Time stamp
1	164	(semiconductor near laser) and (phase near3 control\$4) and (diffraction near grating) and waveguide	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/07/25 14:57
-	266	372/27.ccls.	USPAT; US-PGPUB	2003/07/25 14:55
-	871	372/96.ccls.	USPAT; US-PGPUB	2002/12/28 11:15
-	751	372/43.ccls.	USPAT; US-PGPUB	2002/12/28 11:15
-	7	372/29.016.ccls.	USPAT; US-PGPUB	2002/12/28 11:17
-	46	372/96.ccls. and 372/43.ccls.	USPAT; US-PGPUB	2002/12/28 11:17
-	5	372/27.ccls. and 372/43.ccls.	USPAT; US-PGPUB	2002/12/28 11:32
-	1	372/43.ccls. and te and tm and (phase near control\$4) and (dfb or grating or grading or (diffraction near (grating or grading)))	USPAT; US-PGPUB	2002/12/28 12:06
-	1	372/43.ccls. and te and tm and (phase near control\$4) and ((diffraction near grating) or dfb)	USPAT; US-PGPUB	2002/12/28 12:07
-	65	laser and te and tm and (phase near control\$4) and ((diffraction near grating) or dfb)	USPAT; US-PGPUB	2002/12/28 12:07
-	1	("5757840").PN.	USPAT; US-PGPUB	2002/12/28 14:05